



ZXTD617MC

DUAL 15V NPN LOW SATURATION TRANSISTORS

Features and Benefits

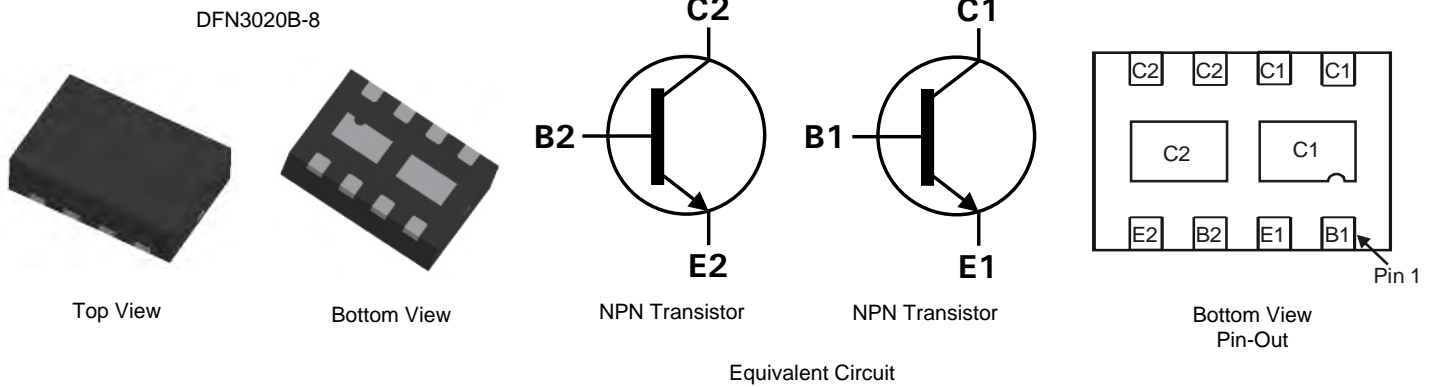
- $BV_{CEO} > 15V$
- $I_C = 4.5A$ Continuous Collector Current
- Low Saturation Voltage (100mV max @ 1A)
- $R_{SAT} = 45 m\Omega$ for a Low Equivalent On-Resistance
- h_{FE} specified up to 12A for high current gain hold up
- Dual NPN saving footprint and component count
- Low profile 0.8mm high package for thin applications
- $R_{\theta JA}$ efficient, 40% lower than SOT26
- 6mm² footprint, 50% smaller than TSOP6 and SOT26
- **Lead-Free, RoHS Compliant (Note 1)**
- **Halogen and Antimony Free. "Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: DFN3020B-8
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe
- UL Flammability Rating 94V-0
- Nominal Package Height: 0.8mm
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.013 grams (approximate)

Applications

- DC-DC Converters
- Charging circuits
- Motor control
- Power switches
- Portable applications



Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD617MCTA	DAA	7	8	3000

Notes: 1. No purposefully added lead.
2. Diodes Inc's "Green" Policy can be found on our website at <http://www.diodes.com>

Marking Information



DAA = Product type marking code
Top view, dot denotes pin 1

Maximum Ratings @ T_A = 25°C unless otherwise specified

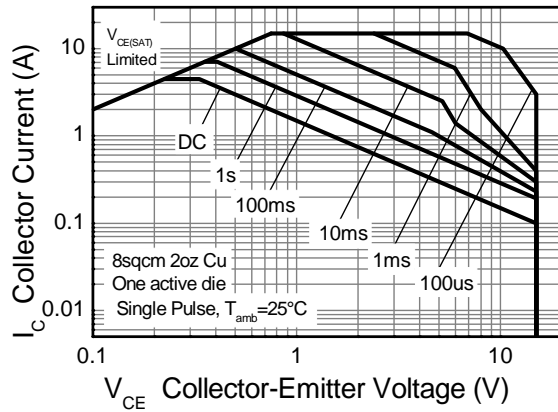
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	40	V
Collector-Emitter Voltage	V _{CEO}	15	
Emitter-Base Voltage	V _{EBO}	7	
Peak Pulse Current	I _{CM}	15	A
Continuous Collector Current	I _C	(Notes 3 & 6) 4.5	
		(Notes 4 & 6) 5	
Base Current	I _B	1	

Thermal Characteristics @ T_A = 25°C unless otherwise specified

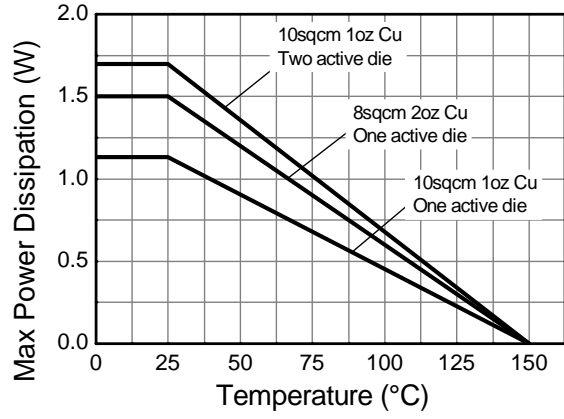
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P _D	(Notes 3 & 6) 1.5	W mW/°C
		(Notes 4 & 6) 12	
		(Notes 5 & 6) 2.45	
		(Notes 5 & 7) 19.6	
		(Notes 5 & 7) 1.13	
Thermal Resistance, Junction to Ambient	R _{θJA}	8	°C/W
		(Notes 3 & 6) 1.7	
		(Notes 4 & 6) 13.6	
		(Notes 5 & 6) 83.3	
Thermal Resistance, Junction to Lead	R _{θJL}	(Notes 5 & 7) 51.0	°C/W
		(Notes 6 & 8) 111	
Operating and Storage Temperature Range	T _J , T _{STG}	73.5	°C
		-55 to +150	

- Notes:
3. For a dual device surface mounted on 28mm x 28mm (8cm²) FR4 PCB with high coverage of single sided 2 oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The heatsink is split in half with the exposed collector pads connected to each half.
 4. Same as note (3), except the device is measured at t <5 sec.
 5. Same as note (3), except the device is surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper.
 6. For a dual device with one active die.
 7. For dual device with 2 active die running at equal power.
 8. Thermal resistance from junction to solder-point (at the end of the collector lead).

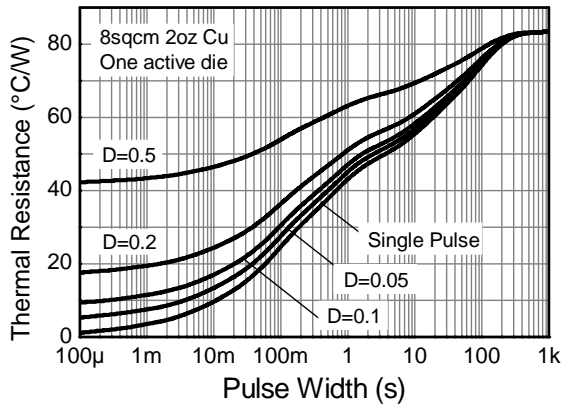
Thermal Characteristics



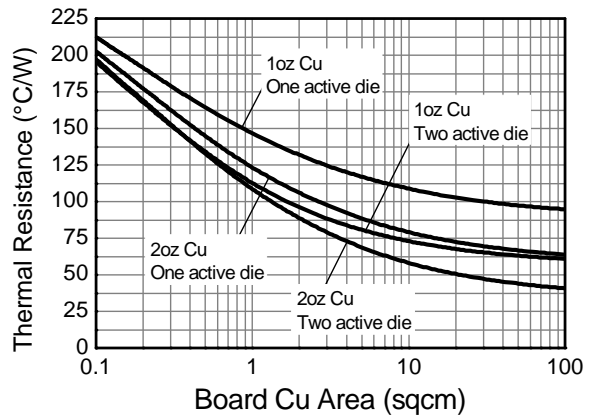
Safe Operating Area



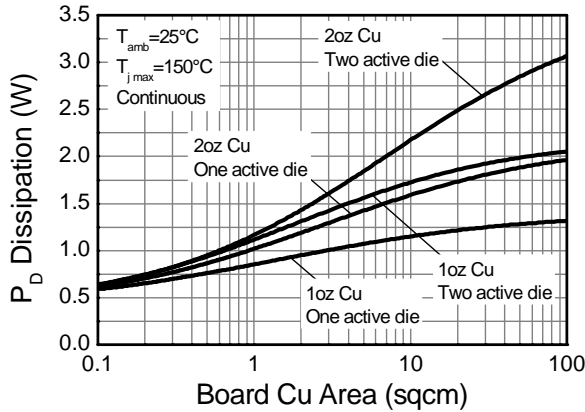
Derating Curve



Transient Thermal Impedance



Thermal Resistance v Board Area



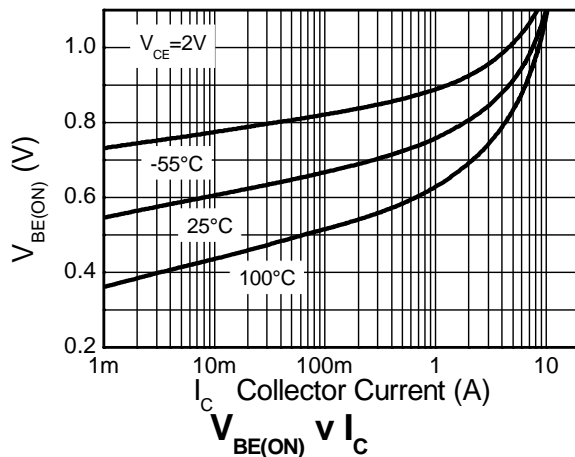
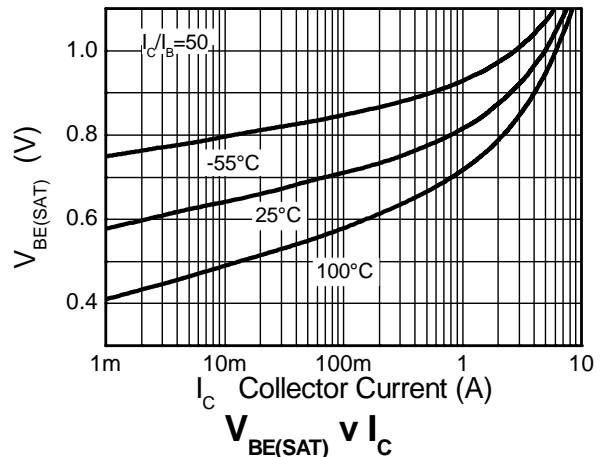
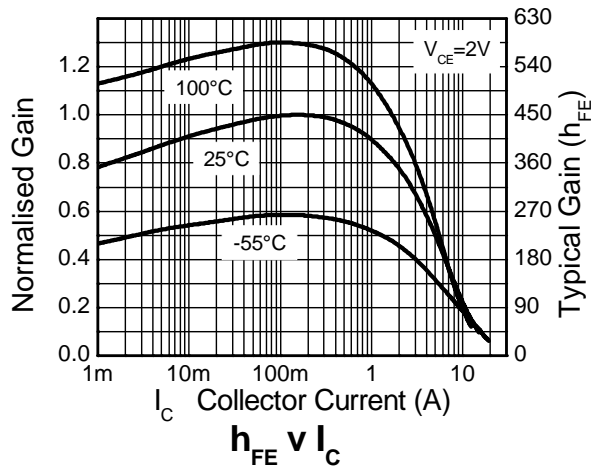
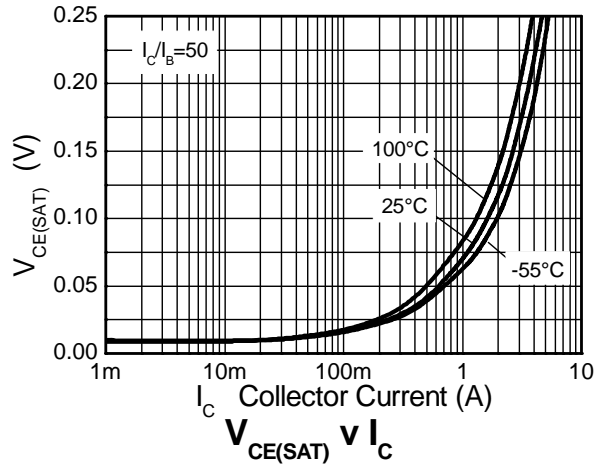
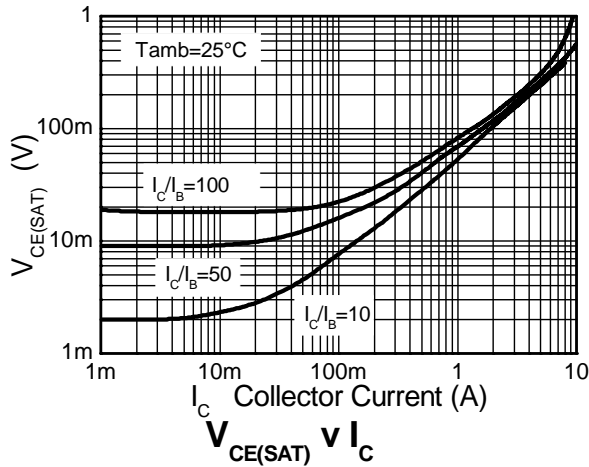
Power Dissipation v Board Area

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

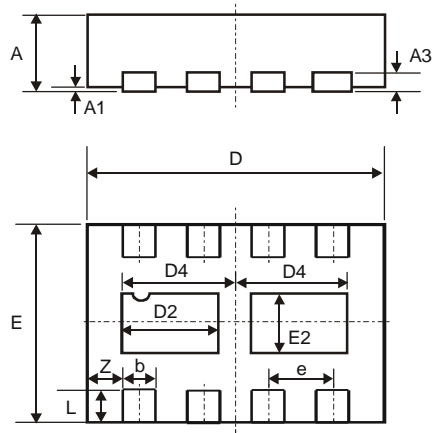
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	40	70	-	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	15	18	-	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.2	-	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CBO}	-	-	100	nA	$V_{CB} = 30\text{V}$
Emitter Cutoff Current	I_{EBO}	-	-	100	nA	$V_{EB} = 6\text{V}$
Collector Emitter Cutoff Current	I_{CES}	-	-	100	nA	$V_{CES} = 12\text{V}$
Static Forward Current Transfer Ratio (Note 9)	h_{FE}	200	415	-	-	$I_C = 10\text{mA}, V_{CE} = 2\text{V}$
		300	450	-	-	$I_C = 200\text{mA}, V_{CE} = 2\text{V}$
		200	320	-	-	$I_C = 3\text{A}, V_{CE} = 2\text{V}$
		150	240	-	-	$I_C = 5\text{A}, V_{CE} = 2\text{V}$
		-	80	-	-	$I_C = 12\text{A}, V_{CE} = 2\text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	-	8	14	mV	$I_C = 0.1\text{A}, I_B = 10\text{mA}$
		-	70	100	mV	$I_C = 1\text{A}, I_B = 10\text{mA}$
		-	165	200	mV	$I_C = 3\text{A}, I_B = 50\text{mA}$
		-	240	310	mV	$I_C = 4.5\text{A}, I_B = 50\text{mA}$
		-	200	-	mV	$I_C = 4.5\text{A}, I_B = 100\text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(on)}$	-	0.88	0.96	V	$I_C = 4.5\text{A}, V_{CE} = 2\text{V}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	0.94	1.05	V	$I_C = 4.5\text{A}, I_B = 50\text{mA}$
Output Capacitance	C_{obo}	-	30	40	pF	$V_{CB} = 10\text{V}, f = 1\text{MHz}$
Transition Frequency	f_T	80	120	-	MHz	$V_{CE} = 10\text{V}, I_C = 50\text{mA}, f = 100\text{MHz}$
Turn-on Time	t_{on}	-	120	-	ns	$V_{CC} = 10\text{V}, I_C = 1\text{A}$
Turn-off Time	t_{off}	-	160	-	ns	$I_{B1} = I_{B2} = 10\text{mA}$

Notes: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$

Typical Electrical Characteristics

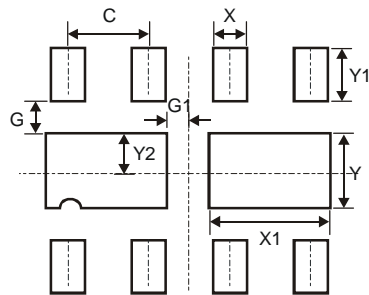


Package Outline Dimensions



DFN3020B-8			
Dim	Min	Max	Typ
A	0.77	0.83	0.80
A1	0	0.05	0.02
A3	-	-	0.15
b	0.25	0.35	0.30
D	2.95	3.075	3.00
D2	0.82	1.02	0.92
D4	1.01	1.21	1.11
e	-	-	0.65
E	1.95	2.075	2.00
E2	0.43	0.63	0.53
L	0.25	0.35	0.30
Z	-	-	0.375
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
C	0.650
G	0.285
G1	0.090
X	0.400
X1	1.120
Y	0.730
Y1	0.500
Y2	0.365

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